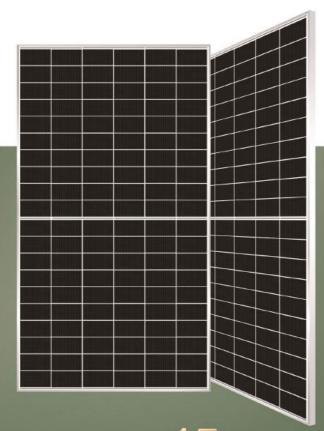


CG SOLAR Product Manual

A LEADER IN SPREADING CLEAN ENERGY







15 YRS Product Warranty

JUYRS

Linear Power Warranty

Legend CG-210-120

120-cell Bifacial HJT Half Cell Double-glass Solar Module

625W~645W



Higher yield

Only four steps for the core process, to reduce labor, operation and maintenance costs.



Higher power generation

Double-sided rate up to 95%, the temperature coefficient is -0.24% $^{\prime}\text{C},$ lower the attenuation rate, no PID and LID effect.



Higher ROI

Double-sided symmetrical structure reduces the mechanical stress of the silicon wafer, improves the whole wafer ratio, and the low temperature process is conducive to thinning.



Higher efficiency

HJT cells mainly absorb infrared light, open the ceiling of theoretical conversion efficiency superimposed with perovskite cells.



Less heat damage

The ambient temperature of the whole process is below 200°C, and the low temperature process reduces heat damage and saves fuel.



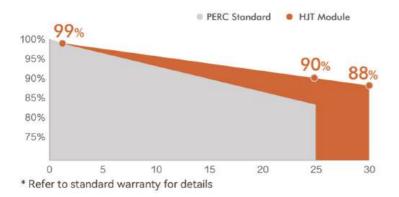
Lower carbon emissions

Higher conversion efficiency, ultra-thin applications, and low temperature manufacturing processes reduce carbon emissions from single silicon wafers.



Suitable for Utility project

Lower BOS cost, lower LCOE.





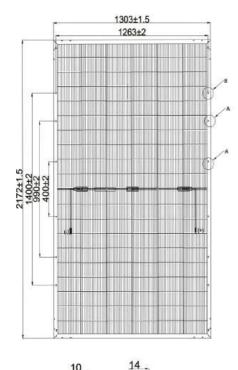








Unit: mm



Electrical Characteristics (STC*)

W	625	630	635	640	645		
V			1,500				
٧	45.13	45.30	45.48	45.65	45.82		
Α	17.31	17.37	17.43	17.49	17.55		
٧	37,86	38.03	38.19	38.35	38.51		
Α	16.51	16.57	16.63	16.69	16.75		
%	22.08	22.26	22.44	22.61	22.79		
Α			35				
Operating Module Temperature		-40~+85°C					
W	0~+5						
%	95						
	V V A V A A A Urre W	V 45.13 A 17.31 V 37.86 A 16.51 % 22.08 A ure	V 45.13 45.30 A 17.31 17.37 V 37.86 38.03 A 16.51 16.57 % 22.08 22.26 A ure	V 1,500 V 45.13 45.30 45.48 A 17.31 17.37 17.43 V 37.86 38.03 38.19 A 16.51 16.57 16.63 % 22.08 22.26 22.44 A 35 oure -40~+85°C W 0~+5	V 1,500 V 45.13 45.30 45.48 45.65 A 17.31 17.37 17.43 17.49 V 37.86 38.03 38.19 38.35 A 16.51 16.57 16.63 16.69 % 22.08 22.26 22.44 22.61 A 35 ure -40~+85°C W 0~+5		

^{*}STC Irradiance 1000 W/m², cell temperature 25°C AM=1.5. Tolerance of Pmax is within +/-3%.

BSTC** Maximum Power W 697 702 708 713 Open Circuit Voltage 45.13 45.30 45.48 45.65 Short Circuit Current 19.30 19.36 19.43 19.50 A Optimum Operating Voltage V 37.86 38.03 38.19 38.35

18.47

18.54

18.60

719

45.82

19.56

38.51

18.67

18.40

Temperature Characteristics

Nominal Operating Cell Temp.(NOCT)	44±2°C
Temperature Coefficient of Pmax	-0.24%/°C
Temperature Coefficient of Voc	-0.24%/°C
Temperature Coefficient of Isc	0.04%/°C

Safety & Warranty

Safety Class	Class II		
Product Warranty	15 yrs Workmanship		
Performance Warranty	30 yrs Linear Warranty*		

"Less than 1% attenuation in the 1st year, the annual attenuation from the 2nd year is no more than 0.375%, and the power is no less than 88% until the 30th year.

Mechanical Characteristics

Optimum Operating Current A

Cell Type	mm	HJT Mono 210×105mm
Cell Connection		120 (6*20)
Module Dimension	mm	2172*1303*35
Weight	kg	35.3
Junction Box		IP68
Output Cable		4mm ² ,300mm in length, length can be customized/UV resistant
Connectors Type		MC4 original / MC4 compatible
Frame		Anodised aluminum alloy
Front Load	Pa	5400
Rear Load Pa		2400
Glass Thickness		Double glass, 2.0mm

电投传古太阳能科技(无锡)有限公司 Power Investment Chuangu Solar Technology(Wuxi) Ltd

Xinou Road,Qianqiao Street,Huishan District, Wuxi,Jiangsu,China

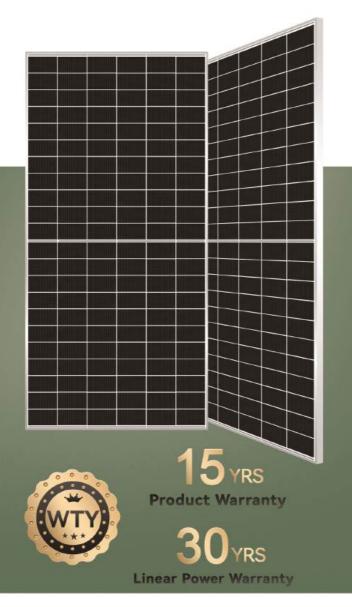


Shipping Configurations

Container Size		40HC	
Pallets Per Container	pcs	18	
Modules Per Pallet	pcs	31	
Modules Per Container		558	

^{**}BSTC:Front side irradiation 1000W/m², back side reflection irradiation 135W/m², AM=1.5, ambient temperature 25°C





Legend CG-210-132

132-cell Bifacial HJT Half Cell Double-glass Solar Module

695W~720W



Higher yield

Only four steps for the core process, to reduce labor, operation and maintenance costs.



Higher power generation

Double-sided rate up to 95%, the temperature coefficient is -0.24% $l^{\circ}\text{C},$ lower the attenuation rate, no PID and LID effect.



Higher ROI

Double-sided symmetrical structure reduces the mechanical stress of the silicon wafer, improves the whole wafer ratio, and the low temperature process is conducive to thinning.



Higher efficiency

HJT cells mainly absorb infrared light, open the ceiling of theoretical conversion efficiency superimposed with perovskite cells.



Less heat damage

The ambient temperature of the whole process is below 200°C, and the low temperature process reduces heat damage and saves fuel.



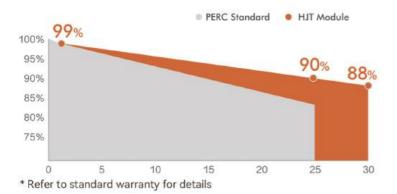
Lower carbon emissions

Higher conversion efficiency, ultra-thin applications, and low temperature manufacturing processes reduce carbon emissions from single silicon wafers.



Suitable for Utility project

Lower BOS cost, lower LCOE.





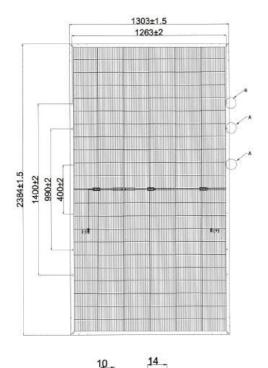








Unit: mm



Electrical Characteristics (STC*)

Maximum Power	W	695	700	705	710	720		
Maximum System Voltage	٧			1,500				
Open Circuit Voltage	٧	49.05	49.14	49.23	49.32	49.41		
Short Circuit Current	Α	17.55	17.63	17.71	17.79	17.89		
Optimum Operating Voltage	٧	43.32	43.39	43.46	43.53	43.60		
Optimum Operating Current	Α.	16.04	16.13	16.22	16,31	16.40		
Conversion Efficiency	%	22.37	22.53	22.70	22.86	23.02		
Fuse Current	Α			35				
Operating Module Temperature		-40~+85°C						
Power Tolerance	W	0~+5						
Bifaciality	%	95						

^{*}STC:Irradiance 1000 W/m³, cell temperature 25°C,AM=1.5. Tolerance of Pmax is within +/-3%.

BSTC**

Maximum Power	W	775	780	786	791	797
Open Circuit Voltage	V	49.05	49,14	49.23	49.32	49.41
Short Circuit Current	Α	19.56	19.65	19.74	19.83	19.94
Optimum Operating Voltage	٧	43.32	43.39	43.46	43.53	43.60
Optimum Operating Current	Α	17.88	17.98	18.08	18.18	18.28

^{**}BSTC:Front side irradiation 1000W/m², back side reflection irradiation 135W/m², AM=1.5, ambient temperature 25°C.

Temperature Characteristics

Nominal Operating Cell Temp.(NOCT)	44±2°C
Temperature Coefficient of Pmax	-0.24%/°C
Temperature Coefficient of Voc	-0.22%/°C
Temperature Coefficient of Isc	0.04%/°C

Mechanical Characteristics

Cell Type mm		HJT Mono 210×105mm
Cell Connection		132 (6*22)
Module Dimension mm		2384*1303*35
Weight	kg	38.7
Junction Box		IP68
Output Cable		4mm²,300mm in length, length can be customized/UV resistant
Connectors Type		MC4 original / MC4 compatible
Frame		Anodised aluminum alloy
Front Load	Pa	5400
Rear Load Pa		2400
Glass Thickness		Double glass, 2.0mm

Safety & Warranty

Safety Class	Class II			
Product Warranty	15 yrs Workmanship			
Performance Warranty	30 yrs Linear Warranty*			

"Less than 1% attenuation in the 1st year, the annual attenuation from the 2nd year is no more than 0.375%, and the power is no less than 88% until the 30th year.

电投传古太阳能科技(无锡)有限公司 Power Investment Chuangu Solar Technology(Wuxi) Ltd

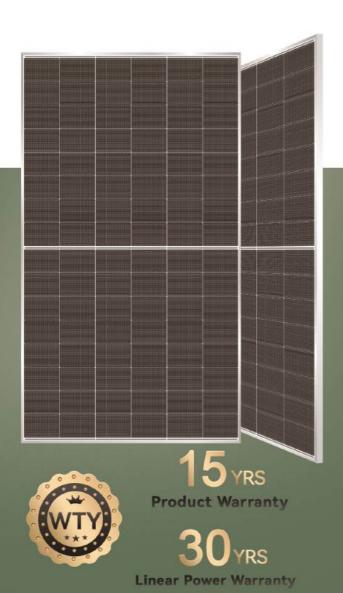
Xinou Road,Qianqiao Street,Huishan District, Wuxi,Jiangsu,China



Shipping Configurations

Container Size		40HC	
Pallets Per Container	pcs	18	
Modules Per Pallet	pcs	31	
Modules Per Container		558	





Legend CG-210R-96

96-cell Bifacial HJT Half Cell Double-glass Solar Module

440W~460W



Higher yield

Only four steps for the core process, to reduce labor, operation and maintenance costs.



Higher power generation

Double-sided rate up to 95%, the temperature coefficient is -0.24% /°C, lower the attenuation rate, no PID and LID effect.



Higher ROI

Double-sided symmetrical structure reduces the mechanical stress of the silicon wafer, improves the whole wafer ratio, and the low temperature process is conducive to thinning.



Higher efficiency

HJT cells mainly absorb infrared light, open the ceiling of theoretical conversion efficiency superimposed with perovskite cells.



Less heat damage

The ambient temperature of the whole process is below 200°C, and the low temperature process reduces heat damage and saves fuel.

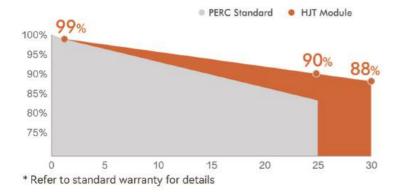


Lower carbon emissions

Higher conversion efficiency, ultra-thin applications, and low temperature manufacturing processes reduce carbon emissions from single silicon wafers.



Suitable for rooftop photovoltaic systems





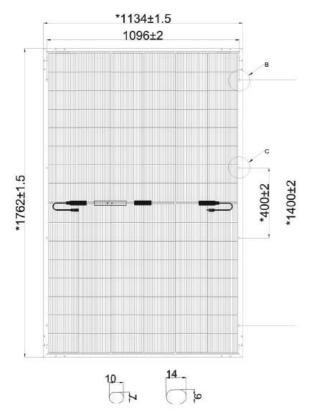








Unit: mm



Maximum Power	W	440	445	450	455	460
Maximum System Voltage	٧			1,500		
Open Circuit Voltage	٧	36.72	36.81	36.90	36.99	37.11
Short Circuit Current	Α	14.98	15.07	15.16	15.25	15.35
Optimum Operating Voltage	٧	30.43	30.49	30.55	30.61	30.67
Optimum Operating Current	Α	14.46	14.53	14.73	14.86	15.00
Conversion Efficiency	%	22.02	22.27	22.52	22.77	23.02
Fuse Current	Α			30		
Operating Module Temperate	ure			-40~+85°C		
Power Tolerance	W			0~+5		

^{*}STC:Irradiance 1000 W/m¹, cell temperature 25°C,AM=1.5. Tolerance of Pmax is within +/-3%.

Electrical Characteristics (STC*)

BSTC**						
Maximum Power	W	490	496	502	507	513
Open Circuit Voltage	٧	36.72	36.81	36.90	36.99	37.11
Short Circuit Current	Α	16.70	16.80	16.90	17.00	17.11
Optimum Operating Voltage	٧	30.43	30.49	30.55	30.61	30.67
Optimum Operating Current	Α	16.12	16.20	16.42	16.57	16.72

^{**}BSTC:Front side irradiation 1000W/m², back side reflection irradiation 135W/m², AM=1.5, ambient temperature 25°C.

Temperature Characteristics

44±2°C
-0.24%/°C
-0.22%/℃
0.04%/°C

Safety & Warranty

Safety Class	Class II
Product Warranty	15 yrs Workmanship
Performance Warranty	30 yrs Linear Warranty*

^{*}Less than 1% attenuation in the 1st year, the annual attenuation from the 2nd year is no more than 0.375%, and the power is no less than 88% until the 30th year.

电投传古太阳能科技(无锡)有限公司 Power Investment Chuangu Solar Technology(Wuxi) Ltd

Xinou Road,Qianqiao Street,Huishan District, Wuxi,Jiangsu,China



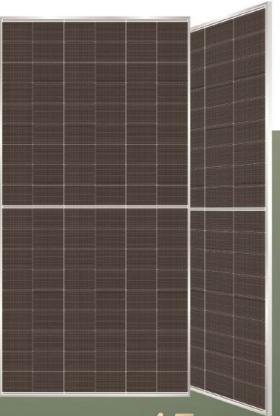
Mechanical Characteristics

Cell Type mm		HJT Mono 182×105mm
Cell Connection		96 (6*16)
Module Dimension	mm	1762*1134*30
Weight kg		23
Junction Box		IP68
Output Cable		4mm²,300mm in length, length can be customized/UV resistant
Connectors Type		MC4 original / MC4 compatible
Frame		Anodised aluminum alloy
Front Load	Pa	5400
Rear Load	Pa	2400
Glass Thickness		Double glass, 1.6mm

Shipping Configurations

Container Size		40HC	
Pallets Per Container	pcs	26	
Modules Per Pallet	pcs	36	
Modules Per Container		936	





[<u>%</u>]

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Legend CG-210R-108

108-cell Bifacial HJT Half Cell Double-glass Solar Module

500W~520W

Higher yield

Only four steps for the core process, to reduce labor, operation and maintenance costs.

Higher power generation

Double-sided rate up to 95%, the temperature coefficient is -0.24% /°C, lower the attenuation rate, no PID and LID effect.

Higher ROI

Double-sided symmetrical structure reduces the mechanical stress of the silicon wafer, improves the whole wafer ratio, and the low temperature process is conducive to thinning.

Higher efficiency

HJT cells mainly absorb infrared light, open the ceiling of theoretical conversion efficiency superimposed with perovskite cells.

Less heat damage

The ambient temperature of the whole process is below 200℃, and the low temperature process reduces heat damage and saves fuel.

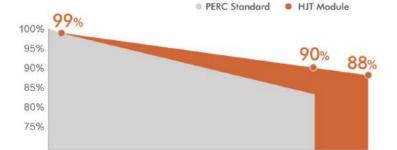
Lower carbon emissions

Higher conversion efficiency, ultra-thin applications, and low temperature manufacturing processes reduce carbon emissions from single silicon wafers.

Suitable for rooftop photovoltaic systems







* Refer to standard warranty for details











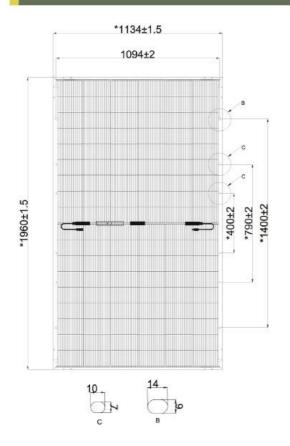
The specification and key features described in this datasheet may deviate slightly and are not guaranteed. Chuangu Solar the right to make any adjustment to the information described herein at any time without notice. Please always obtain thelatest version of the datasheet which shall be duly incorporated into the binding contract made by the parties governing alltransactions related to the purchase and sale of the products described herein.

30

25

20

Unit: mm



Maximum Power	W	500	505	510	515	520			
Maximum System Voltage	٧			1,500					
Open Circuit Voltage	٧	41.35	41.44	41.53	41.63	41.72			
Short Circuit Current	A	15.08	15.17	15.26	15.35	15.44			
Optimum Operating Voltag	e V	34.25	34.31	34.37	34.43	34.49			
Optimum Operating Currer	nt A	14.60	14.72	14.84	14.96	15.08			
Conversion Efficiency	%	22.50	22.72	22.95	23.17	23.40			
Fuse Current	Α			30					
Operating Module Tempera	perating Module Temperature			-40~+85°C					
Power Tolerance	W	0~+5							
Bifaciality	%	95							

^{*}STC:Irradiance 1000 W/m², cell temperature 25°C,AM=1.5. Tolerance of Pmax is within +/-3%.

Electrical Characteristics (STC*)

BSTC**						
Maximum Power	W	557	563	569	574	580
Open Circuit Voltage	V	41.35	41,44	41.53	41.63	41.72
Short Circuit Current	Α	16.81	16.91	17.01	17.11	17.21
Optimum Operating Voltage	V	34.25	34.31	34.37	34.43	34.49
Optimum Operating Current	Α	16.27	16.41	16.54	16.67	16.81

^{**}BSTC:Front side irradiation 1000W/m², back side reflection irradiation 135W/m², AM=1.5, ambient temperature 25°C

Temperature Characteristics

Nominal Operating Cell Temp.(NOCT)	44±2°C
Temperature Coefficient of Pmax	-0.24%/°C
Temperature Coefficient of Voc	-0.22%/°C
Temperature Coefficient of Isc	0.04%/°C

Safety & Warranty

Safety Class	Class II		
Product Warranty	15 yrs Workmanship		
Performance Warranty	30 yrs Linear Warranty*		

^{*}Less than 1% attenuation in the 1st year, the annual attenuation from the 2nd year is no more than 0.375%, and the power is no less than 88% until the 30th year.

Mechanical Characteristics

ell Type mm		HJT Mono 182×105mm
Cell Connection		108 (6*18)
Module Dimension mm		1960*1134*30
Weight	kg	27.6
Junction Box		IP68
Output Cable		4mm²,300mm in length, length can be customized/UV resistant
Connectors Type		MC4 original / MC4 compatible
Frame		Anodised aluminum alloy
Front Load Pa		5400
Rear Load Pa		2400
Glass Thickness		Double glass, 2.0mm

电投传古太阳能科技(无锡)有限公司

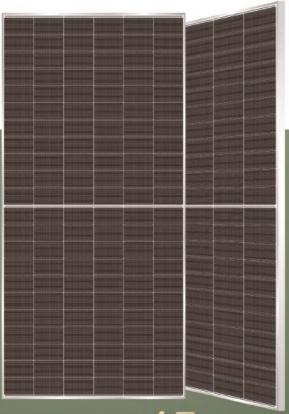
Power Investment Chuangu Solar Technology(Wuxi) Ltd

Xinou Road,Qianqiao Street,Huishan District, Wuxi,Jiangsu,China



Shipping Configurations							
Container Size		40HC					
Pallets Per Container	pcs	22					
Modules Per Pallet	pcs	36					
Modules Per Container		792					





15 YRS Product Warranty

UYRSLinear Power Warranty

Legend CG-210R-132

132-cell Bifacial HJT Half Cell Double-glass Solar Module

605W~625W



Higher yield

Only four steps for the core process, to reduce labor, operation and maintenance costs.



Higher power generation

Double-sided rate up to 95%, the temperature coefficient is -0.24% /°C, lower the attenuation rate, no PID and LID effect.



Higher ROI

Double-sided symmetrical structure reduces the mechanical stress of the silicon wafer, improves the whole wafer ratio, and the low temperature process is conducive to thinning.



Higher efficiency

HJT cells mainly absorb infrared light, open the ceiling of theoretical conversion efficiency superimposed with perovskite cells.



Less heat damage

The ambient temperature of the whole process is below 200°C, and the low temperature process reduces heat damage and saves fuel.

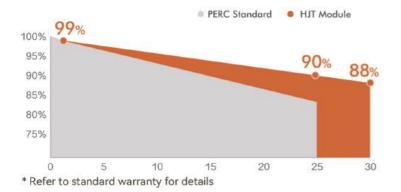


Lower carbon emissions

Higher conversion efficiency, ultra-thin applications, and low temperature manufacturing processes reduce carbon emissions from single silicon wafers.



Suitable for centralized ground power station projects





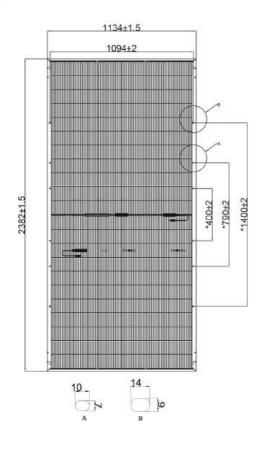








Unit: mm



Electrical Characteristics (STC*)

Maximum Power	W	605	610	615	620	625	
Maximum System Voltage	٧			1,500			
Open Circuit Voltage	٧	48.15	48.24	48.33	48.42	48.51	
Short Circuit Current	Α	15.59	15.68	15.77	15.86	15.95	
Optimum Operating Voltage	٧	40.25	40.33	40.41	40.49	40.57	
Optimum Operating Current	Α	15.03	15.13	15.22	15.31	15.41	
Conversion Efficiency	%	22.38	22.56	22.75	22.93	23.12	
Fuse Current	Α			30			
Operating Module Temperature		-40~+85°C					
Power Tolerance	W			0~+5			
Bifaciality	Bifaciality			95			

^{*}STC:Irradiance 1000 W/m², cell temperature 25°C,AM=1.5. Tolerance of Pmax is within +/-3%.

BSTC**						
W	674	680	686	691	697	
V	48.15	48.24	48.33	48.42	48.51	
Α	17.38	17.48	17.58	17.68	17.78	
٧	40.25	40.33	40.41	40.49	40.57	
Α	16.76	16.86	16.97	17.07	17.17	
	V A V	V 48.15 A 17.38 V 40.25	V 48.15 48.24 A 17.38 17.48 V 40.25 40.33	V 48.15 48.24 48.33 A 17.38 17.48 17.58 V 40.25 40.33 40.41	V 48.15 48.24 48.33 48.42 A 17.38 17.48 17.58 17.68 V 40.25 40.33 40.41 40.49	

^{**}BSTC:Front side irradiation 1000W/m², back side reflection irradiation 135W/m², AM=1.5, ambient temperature 25°C

Temperature Characteristics

Nominal Operating Cell Temp.(NOCT)	44±2°C
Temperature Coefficient of Pmax	-0.24%/°C
Temperature Coefficient of Voc	-0.22%/°C
Temperature Coefficient of Isc	0.04%/°C

Safety & Warranty

Safety Class	Class II		
Product Warranty	15 yrs Workmanship		
Performance Warranty	30 yrs Linear Warranty*		

^{*}Less than 1% attenuation in the 1st year, the annual attenuation from the 2nd year is no more than 0.375%, and the power is no less than 88% until the 30th year,

Mechanical Characteristics

Cell Type	mm	HJT Mono 182×105mm
Cell Connection		132 (6*22)
Module Dimension	mm	2382*1134*30
Weight	kg	33.6
Junction Box		IP68
Output Cable		4mm²,300mm in length, length can be customized/UV resistant
Connectors Type		MC4 original / MC4 compatible
Frame		Anodised aluminum alloy
Front Load	Pa	5400
Rear Load	Pa	2400
Glass Thickness		Double glass, 2.0mm

电投传古太阳能科技(无锡)有限公司 Power Investment Chuangu Solar Technology(Wuxi) Ltd

Xinou Road,Qianqiao Street,Huishan District, Wuxi,Jiangsu,China



Shipping Configurations Container Size 40HC Pallets Per Container pcs 20 Modules Per Pallet pcs 36 Modules Per Container 720